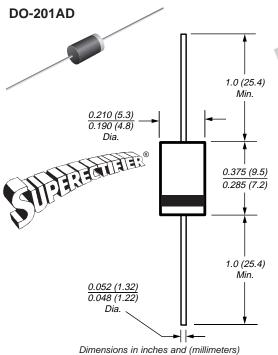


New Product

Vishay Semiconductors formerly General Semiconductor

Glass Passivated Junction Plastic Rectifiers

Reverse Voltage 200 to 1300V Forward Current 3.0A



Dimensions in inches and (millimeters)

*Glass-plastic encapsulation technique is covered by
Patent No. 3,996,602 and brazed-lead assembly by Patent No. 3,930,306

Features

- Plastic package has Underwriters Laboratories Flammability Classification 94V-0
- High temperature metallurgically bonded construction
- Cavity-free glass passivated junction
- Capable of meeting environmental standards of MIL-S-19500
- 3.0 Ampere operation at TA=55°C with no thermal runaway
- Typical I_R less than 0.1μA
- High temperature soldering guaranteed: 350°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

Mechanical Data

Case: JEDEC DO-201AD, molded plastic over glass body

Terminals: Plated axial leads, solderable per

MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any Weight: 0.04 oz., 1.12 g Packaging Codes/Options:

1/Bulk – 1.5K per container, 15K/box

4/1.4K per 13" reel, 5.6K/box 23/1K per ammo mag., 9K/box

Maximum Ratings & Thermal Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	BY251GP	BY252GP	BY253GP	BY254GP	BY255GP	Unit
Maximum repetitive peak reverse voltage	VRRM	200	400	600	800	1300	V
Maximum RMS voltage	VRMS	140	280	420	560	910	V
Maximum DC blocking voltage	VDC	200	400	600	800	1300	V
Maximum average forward rectified current 10mm lead length at T _A = 55°C	IF(AV)	3.0				А	
Peak forward surge current 10ms single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	100				А	
Maximum full load reverse current, full cycle average 10mm lead length at T _A = 55°C	I _{R(AV)}	100				μΑ	
Typical thermal resistance ⁽¹⁾	Roja Rojl	20 10				°C/W	
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +175				°C	

Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Maximum instantaneous forward voltage at 3.0A	VF	1.1	V
Maximum reverse current at rated DC blocking voltage T _A = 25°C	IR	5.0	μА
Typical reverse recovery time IF = 0.5A, IR = 1.0V, Irr = 0.25A	trr	3.0	μs
Typical junction capacitance at 4.0V, 1MHz	CJ	40	pF

Note: (1) Thermal resistance from junction to ambient and from junction to lead at 0.375" (9.5mm) lead length, P.C.B. mounted

BY251GP thru BY255GP

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Ratings and

Characteristic Curves (TA = 25°C unless otherwise noted)

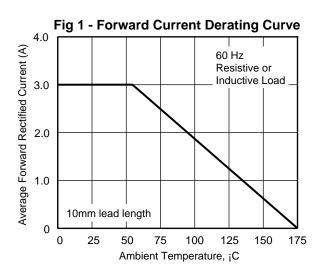
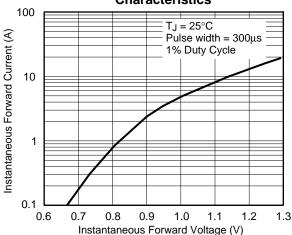


Fig 3 - Typical Instantaneous Forward Characteristics



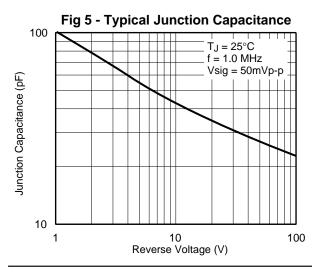


Fig 2 - Maximum Non-repetitive Peak

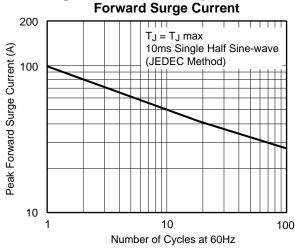
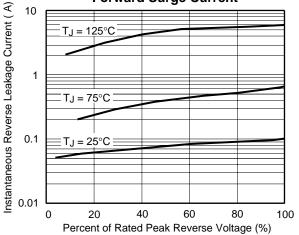


Fig 2 - Maximum Non-repetitive Peak Forward Surge Current



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